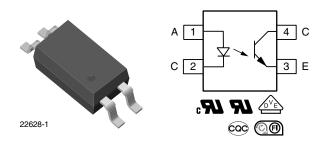


## Vishay Semiconductors

# Optocoupler, Phototransistor Output, SSOP-4, Half Pitch, Mini-Flat Package



## **DESCRIPTION**

The VOS615B series has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4-pin 50 mil lead pitch mini-flat package.

It features a high current transfer ratio at low input current, low coupling capacitance, and high isolation voltage.

The coupling devices are designed for signal transmission between two electrically separated circuits.

### **FEATURES**

- High CTR with low input current
- · SSOP low profile package (half pitch)
- High collector emitter voltage, V<sub>CEO</sub> = 80 V
- Isolation test voltage = 3750 V<sub>RMS</sub>
- · Low coupling capacitance
- · High common mode transient immunity
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





COMPLIANT
HALOGEN
FREE
GREEN
(5-2008)

## **APPLICATIONS**

- Telecom
- · Industrial controls
- · Battery powered equipment
- · Office machines
- · Programmable controllers

#### **AGENCY APPROVALS**

Safety application model number covering all products in this datasheet is VOS615B. This model number should be used when consulting safety agency documents.

- UL1577, file no. E76222, double protection
- cUL, accordance to CSA component acceptance service no. 5A, double protection
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- FIMKO EN 60950-1
- CQC GB4943.1-2011 and GB8898-2011 (suitable for installation altitude below 2000 m)

| ORDERING INFORMATION                |               |                |                     |                |  |  |
|-------------------------------------|---------------|----------------|---------------------|----------------|--|--|
| V O S 6 1 5  PART NUMBER            | B - # CTR BIN | X 0 0 [        | TAPE<br>AND<br>REEL | SSOP-4         |  |  |
| AGENCY CERTIFIED/PACKAGE            | CTR (%)       |                |                     |                |  |  |
| AGENOT GENTIFIED/FAGRAGE            | 10 mA         |                |                     |                |  |  |
| UL, cUL, FIMKO, CQC                 | 50 to 600     | 63 to 125      | 100 to 200          | 160 to 320     |  |  |
| SSOP-4, 50 mil pitch                | VOS615BT      | -              | VOS615B-3T          | -              |  |  |
| UL, CUL, FIMKO, CQC, VDE (option 1) | 50 to 600     | 63 to 125      | 100 to 200          | 160 to 320     |  |  |
| SSOP-4, 50 mil pitch                | VOS615B-X001T | VOS615B-2X001T | VOS615B-3X001T      | VOS615B-4X001T |  |  |

#### Note

Additional options may be possible, please contact sales office.

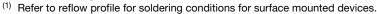


# www.vishay.com Vishay Semiconductors

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                        |                   |             |           |  |  |
|--|------------------------|-------------------|-------------|-----------|--|--|
| PARAMETER  | TEST CONDITION         | SYMBOL            | VALUE       | UNIT      |  |  |
| INPUT  |                        |                   |             |           |  |  |
| Reverse voltage  |                        | V <sub>R</sub>    | 6           | V         |  |  |
| Power dissipation  |                        | P <sub>diss</sub> | 100         | mW        |  |  |
| Forward current  |                        | I <sub>F</sub>    | 60          | mA        |  |  |
| Surge forward current  | t <sub>p</sub> ≤ 10 μs | I <sub>FSM</sub>  | 1.5         | Α         |  |  |
| Junction temperature   |                        | T <sub>j</sub>    | 125         | °C        |  |  |
| OUTPUT   | •                      |                   |             |           |  |  |
| Collector emitter voltage  |                        | V <sub>CEO</sub>  | 80          | V         |  |  |
| Emitter collector voltage  |                        | V <sub>ECO</sub>  | 7           | V         |  |  |
| Collector current  |                        | Ic                | 50          | mA        |  |  |
| Power dissipation  |                        | P <sub>diss</sub> | 150         | mW        |  |  |
| Junction temperature   |                        | T <sub>j</sub>    | 125         | °C        |  |  |
| COUPLER  |                        |                   |             |           |  |  |
| Isolation test voltage between emitter and detector                                    | t = 1 min              | V <sub>ISO</sub>  | 3750        | $V_{RMS}$ |  |  |
| Total power dissipation  |                        | P <sub>tot</sub>  | 250         | mW        |  |  |
| Storage temperature range  |                        | T <sub>stg</sub>  | -55 to +150 | °C        |  |  |
| Ambient temperature range  |                        | T <sub>amb</sub>  | -55 to +110 | °C        |  |  |
| Soldering temperature (1)  | t = 10 s               | T <sub>sld</sub>  | 260         | °C        |  |  |

#### **Notes**

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.



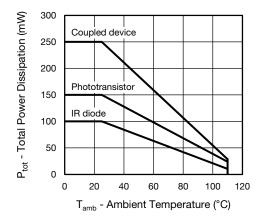


Fig. 1 - Power Dissipation vs. Ambient Temperature

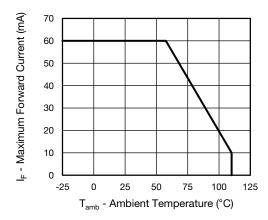


Fig. 2 - Maximum Forward Current vs. Ambient Temperature



## www.vishay.com

# Vishay Semiconductors

| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                    |      |      |      |      |
|--|---|--------------------|------|------|------|------|
| PARAMETER  | TEST CONDITION  | SYMBOL             | MIN. | TYP. | MAX. | UNIT |
| INPUT  |   |                    |      |      |      |      |
| Forward voltage  | $I_F = 5 \text{ mA}$  | $V_{F}$            | -    | 1.18 | 1.5  | V    |
| Reverse current  | V <sub>R</sub> = 6 V  | I <sub>R</sub>     | -    | 0.01 | 10   | μA   |
| Capacitance  | $V_R = 0 V, f = 1 MHz$  | Cı                 | -    | 7.3  | -    | pF   |
| OUTPUT   |   |                    |      |      |      |      |
| Collector emitter leakage current  | V <sub>CE</sub> = 10 V  | I <sub>CEO</sub>   | -    | 0.3  | 100  | nA   |
| Collector emitter breakdown voltage  | I <sub>C</sub> = 100 μA                                       | BV <sub>CEO</sub>  | 80   | -    | -    | V    |
| Emitter collector breakdown voltage  | I <sub>E</sub> = 10 μA  | BV <sub>ECO</sub>  | 7    | -    | -    | V    |
| Collector emitter capacitance  | V <sub>CE</sub> = 5 V, f = 1 MHz                              | C <sub>CE</sub>    | -    | 5    | -    | pF   |
| COUPLER  |   |                    |      |      |      |      |
| Collector emitter saturation voltage   | $I_F = 5 \text{ mA}, I_C = 2.5 \text{ mA}$                    | V <sub>CEsat</sub> | -    | 0.25 | 0.4  | V    |
| Cut-off frequency  | $I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 100 \Omega$ | f <sub>ctr</sub>   | -    | 155  | -    | kHz  |

#### Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

| CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |           |        |      |      |      |      |
|---|---|-----------|--------|------|------|------|------|
| PARAMETER   | TEST CONDITION                                | PART      | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| I <sub>C</sub> /I <sub>F</sub>  | I <sub>F</sub> = 10 mA, V <sub>CE</sub> = 5 V | VOS615B   | CTR    | 50   | -    | 600  | %    |
|   |   | VOS615B-2 | CTR    | 63   | -    | 125  | %    |
|   |   | VOS615B-3 | CTR    | 100  | -    | 200  | %    |
|   |   | VOS615B-4 | CTR    | 160  | -    | 320  | %    |

| <b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                  |      |      |      |      |  |
|---|---|------------------|------|------|------|------|--|
| PARAMETER   | TEST CONDITION                                | SYMBOL           | MIN. | TYP. | MAX. | UNIT |  |
| NON-SATURATED   |   |                  |      |      |      |      |  |
| Rise and fall time  |   | t <sub>r</sub>   | -    | 3    | -    | μs   |  |
| Fall time   | $I_{C} = 2 \text{ mA}, V_{CC} = 5 \text{ V},$ | t <sub>f</sub>   | -    | 3    | -    | μs   |  |
| Turn-on time  | $R_L = 100 \Omega$                            | t <sub>on</sub>  | -    | 6    | -    | μs   |  |
| Turn-off time   |   | t <sub>off</sub> | -    | 4    | -    | μs   |  |
| SATURATED   |   |                  |      |      |      |      |  |
| Rise and fall time  |   | t <sub>r</sub>   | -    | 3    | -    | μs   |  |
| Fall time   | $I_F = 1.6 \text{ mA}, V_{CC} = 5 \text{ V},$ | t <sub>f</sub>   | -    | 12   | -    | μs   |  |
| Turn-on time  | $R_L = 1.9 \text{ k}\Omega$                   | t <sub>on</sub>  | -    | 4    | -    | μs   |  |
| Turn-off time   |   | t <sub>off</sub> | -    | 18   | -    | μs   |  |

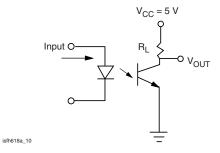


Fig. 3 - Test Circuit

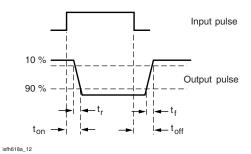


Fig. 4 - Test Circuit and Waveforms



# www.vishay.com Vishay Semiconductors

| PARAMETER  | TEST CONDITION   | SYMBOL          | VALUE            | UNIT              |
|--|--|-----------------|------------------|-------------------|
| Climatic classification (according to IEC 68 part 1)         |  |                 | 55/110/21        |                   |
| Comparative tracking index                                   |  | CTI             | 175              |                   |
| Maximum rated withstanding isolation voltage                 | 40 % to 60 % RH, AC test of 1 min  | $V_{ISO}$       | 3750             | V <sub>RMS</sub>  |
| Maximum transient isolation voltage                          |  | $V_{IOTM}$      | 6000             | V                 |
| Maximum repetitive peak isolation voltage                    |  | $V_{IORM}$      | 707              | V                 |
| Insulation resistance  | V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C   | R <sub>IO</sub> | 10 <sup>11</sup> | Ω                 |
| Isolation resistance (under fault conditions)                | $V_{IO} = 500 \text{ V}, T_{amb} = T_{SI}$   | R <sub>IO</sub> | 10 <sup>9</sup>  | Ω                 |
| Output safety power  |  | $P_{SO}$        | 350              | mW                |
| Input safety current   |  | I <sub>SI</sub> | 200              | mA                |
| Input safety temperature                                     |  | $T_{SI}$        | 175              | °C                |
| Apparent charge test voltage (method A)                      | $V_{IORM}$ x 1.6 = $V_{PR}$ , type and sample test $t_m$ = 60 s, partial discharge < 5 pC        | $V_{PR}$        | 1132             | V <sub>peak</sub> |
| Apparent charge test voltage (method B)                      | $V_{IORM}$ x 1.875 = $V_{PR}$ , 100 % production test with $t_m$ = 1 s, partial discharge < 5 pC | $V_{PR}$        | 1326             | V <sub>peak</sub> |
| Creepage distance  |  |                 | ≥ 5              | mm                |
| Clearance distance   |  |                 | ≥ 5              | mm                |
| Insulation thickness   |  | DTI             | ≥ 0.4            | mm                |
| Environment (pollution degree in accordance to DIN VDE 0109) |  |                 | 2                |                   |

#### Note

## TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

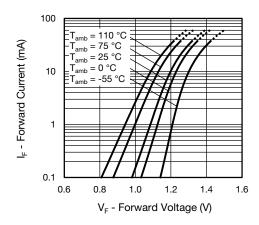


Fig. 5 - Forward Voltage vs. Forward Current

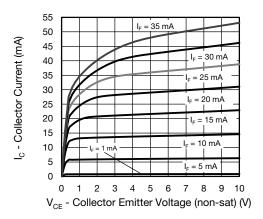
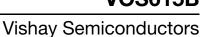


Fig. 6 - Collector Current vs. Collector Emitter Voltage

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.





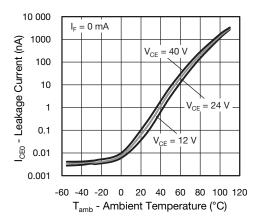


Fig. 7 - Leakage Current vs. Ambient Temperature

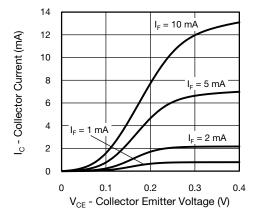


Fig. 8 - Collector Current vs. Collector Emitter Voltage

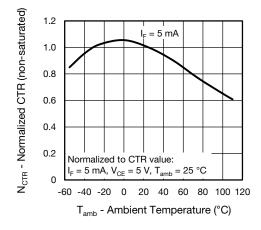


Fig. 9 - Normalized Current Transfer Ratio (non-saturated) vs.

Ambient Temperature

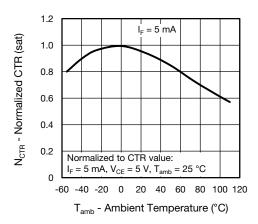


Fig. 10 - Normalized Current Transfer Ratio (saturated) vs.
Ambient Temperature

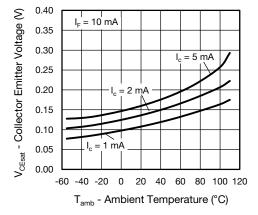


Fig. 11 - Collector Emitter Voltage vs. Ambient Temperature

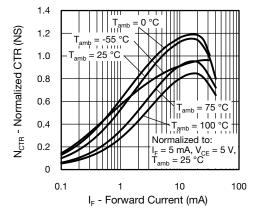


Fig. 12 - Normalized CTR (non-saturated) vs. Forward Current



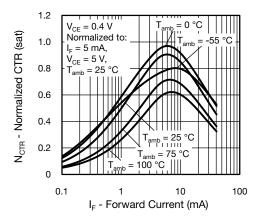


Fig. 13 - Normalized CTR (saturated) vs. Forward Current

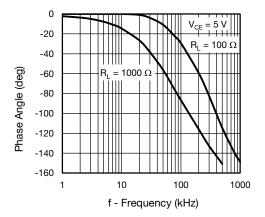


Fig. 14 - F<sub>CTR</sub> vs. Phase Angle

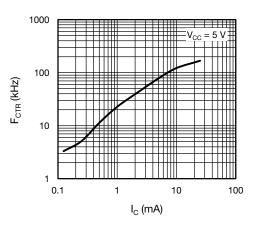


Fig. 15 - F<sub>CTR</sub> vs. Collector Current

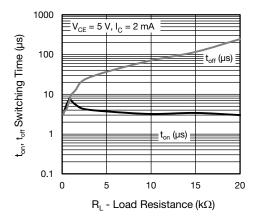
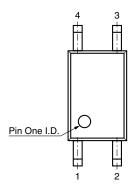


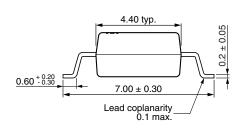
Fig. 16 - Switching Time vs. Load Resistance

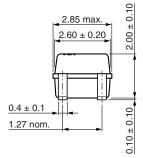


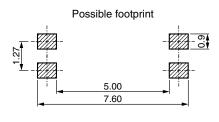
# Vishay Semiconductors

## **PACKAGE DIMENSIONS** (in millimeters)

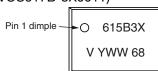








## PACKAGE MARKING (example of VOS617B-3X001T)



#### Notes

- Option 1 is reflected with letter "X".
- Tape and reel suffix (T) is not part of the package marking.



## PACKAGING INFORMATION (TAPE AND REEL) (in millimeters)

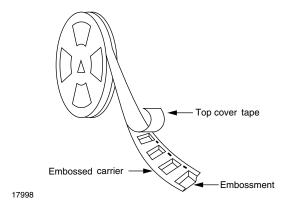


Fig. 17 - Tape and Reel Shipping Medium

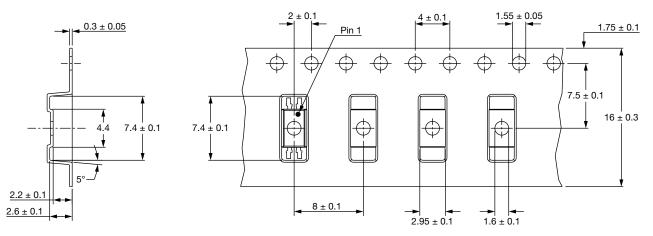


Fig. 18 - Tape and Reel Packing (3000 parts per reel)

#### **SOLDER PROFILES**

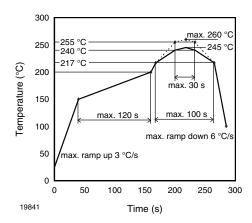


Fig. 19 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

## HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions:  $T_{amb}$  < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



## **Legal Disclaimer Notice**

Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Transistor Output Optocouplers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below:

LTV-814S-TA LTV-824HS 66095-001 6N136-X017T MCT6-X007 MOC8101-X017T PS2561A-1-W-A PS2561B-1-L-A PS2561L-1-V-A MRF658 IL755-1X007 ILD2-X006 ILD74-X001 ILQ615-2X017 ILQ615-3X016 LDA102S LDA110S PS2561-1-V-W-A PS2561AL-1-V-A PS2561L1-1-L-A PS2701A-1-F3-P-A PS2801-1-F3-P-A PS2911-1-L-AX CNY17-2X017 CNY17-4X001 CNY17-4X017 CNY17F-1X007 CNY17F-2X017 CNY17F-4X001 CNY17G-1 LTV-214 LTV-702VB LTV-733S LTV-816S-TA LTV-825S TCET1113 TCET2100 4N25-X007T IL215AT ILD615-1X007 ILQ2-X007 VOS615A-2T WPPC-A11066AA WPPC-A11066AD WPPC-A11084ASS WPPC-A21068AA WPPC-D21068AD WPPC-D21068ED WPPC-D410616EA WPPC-D410616ED